Product Preview **Hybrid Power Module** Integrated Power Stage for 5.0 hp 460 VAC Motor Drive

This module integrates a 3-phase inverter, 3-phase rectifier, brake, and temperature sense in a single convenient package. It is designed for 5.0 hp general purpose 3-phase induction motor drive applications. The inverter incorporates advanced insulated gate bipolar transistors (IGBT) matched with fast soft free-wheeling diodes to give optimum performance. The solderable top connector pins are designed for easy interfacing to the user's control board.

- Short Circuit Rated 10 μs @ 125°C, 720 V
- Pin-to-Baseplate Isolation Exceeds 2500 Vac (rms)
- Compact Package Outline
- Access to Positive and Negative DC Bus
- Independent Brake Circuit Connections
- UL Recognition Pending

ORDERING INFORMATION

| Device | Voltage | Current | Equivalent | |
|-----------------|---------|---------|------------|--|
| | Rating | Rating | Horsepower | |
| PHPM7A25S120DC3 | 1200 | 25 | 5.0 | |

MAXIMUM DEVICE RATINGS (T_J = 25°C unless otherwise noted)

| Rating | Symbol | Value | Unit | |
|---|---------------------------|-------------|-------|--|
| Repetitive Peak Input Rectifier Reverse Voltage ($T_J = 25^{\circ}C$ to $150^{\circ}C$) | VRRM | 900 | V | |
| Non–Repetitive Peak Input Rectifier Reverse Voltage ⁽¹⁾ ($T_J = 25^{\circ}C$ to $150^{\circ}C$) | VRSM | 1600 | V | |
| IGBT Reverse Voltage | VCES | 1200 | V | |
| Gate-Emitter Voltage | V _{GES} | ±20 | V | |
| Continuous IGBT Collector Current (T _C = 80°C) | ICmax | 25 | A | |
| Repetitive Peak IGBT Collector Current (2) | I _{C(pk)} | 50 | A | |
| Continuous Free–Wheeling Diode Current ($T_{C} = 25^{\circ}C$) | IFmax | 25 | А | |
| Continuous Free–Wheeling Diode Current (T _C = 80°C) | IF80 | 16.5 | A | |
| Repetitive Peak Free–Wheeling Diode Current (2) | IF(pk) | 50 | А | |
| Average Converter Output Current (Peak–to–Average ratio of 10, T_{C} = 95°C) | IOmax | 23.4 | A | |
| IGBT Power Dissipation per die ($T_C = 95^{\circ}C$) | PD | 50 | W | |
| Free–Wheeling Diode Power Dissipation per die ($T_{C} = 95^{\circ}C$) | PD | 23 | W | |
| Junction Temperature Range | TJ | -40 to +150 | °C | |
| Short Circuit Duration (V_{CE} = 720 V, T_J = 125°C) | t _{sc} | 10 | μs | |
| Isolation Voltage, pin to baseplate | VISO | 2500 | Vac | |
| Operating Case Temperature Range | T _C -40 to +95 | | °C | |
| Storage Temperature Range | T _{stg} | -40 to +150 | °C | |
| Mounting Torque — Heat Sink Mounting Holes | _ | 12 | lb–in | |

(1) Half-Sine 60 Hz, maximum reverse voltage capability decreases by 0.1% per °C at lower temperature

(2) 1.0 ms = 1.0% duty cycle

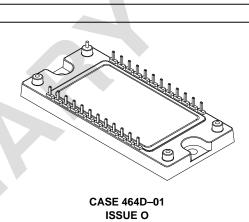
Preferred devices are Motorola recommended choices for future use and best overall value.

This document contains information on a product under development. Motorola reserves the right to change or discontinue this product without notice.



25 AMP. 1200 VOLT

HYBRID POWER MODULE



MHPM7A25S120DC3

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|----------------------|-------|-------|-------|-------|
| DC AND SMALL SIGNAL CHARACTERISTICS | • | | | | |
| Input Rectifier Forward Voltage (IF = 25 A) | VF | — | 1.1 | 1.375 | V |
| Gate–Emitter Leakage Current (V _{CE} = 0 V, V _{GE} = \pm 20 V) | IGES | — | — | ±20 | μΑ |
| Collector–Emitter Leakage Current (V_{CE} = 1200 V, V_{GE} = 0 V) | ICES | — | 5.0 | 100 | μΑ |
| Gate–Emitter Threshold Voltage ($V_{CE} = V_{GE}$, $I_{C} = 1.0$ mA) | V _{GE(th)} | 4.0 | 6.0 | 8.0 | V |
| Collector–Emitter Breakdown Voltage (I _C = 10 mA, V_{GE} = 0 V) | V(BR)CES | 1200 | — | — | V |
| Collector–Emitter Saturation Voltage ($I_C = I_{Cmax}$, $V_{GE} = 15$ V) | V _{CE(sat)} | — | 2.5 | 3.5 | V |
| Free–Wheeling Diode Forward Voltage ($I_F = I_{Fmax}$, $V_{GE} = 0$ V) | VF | 1.8 | 2.1 | 2.5 | V |
| Input Capacitance (V _{GE} = 0 V, V _{CE} = 25 V, f = 1.0 MHz) | C _{ies} | | 2700 | — | pF |
| Input Gate Charge (V_{CE} = 600 V, I_{C} = I_{Cmax} , V_{GE} = 15 V) | QT | | 100 | — | nC |
| THERMAL CHARACTERISTICS, EACH DIE | | | | | |
| Thermal Resistance — IGBT | R _θ JC | — | 0.8 | 1.1 | °C/W |
| Thermal Resistance — Free–Wheeling (Fast Soft) Diode | R ₀ JC | - | 1.8 | 2.4 | °C/W |
| Thermal Resistance — Input Rectifier | R _θ JC | — | 2.4 | 3.3 | °C/W |
| TEMPERATURE SENSE DIODE | | • | - | | |
| Forward Voltage (@ I _F = 1.0 mA) | VF | 1.983 | 2.024 | 2.066 | V |
| Forward Voltage Temperature Coefficient (@ I _F = 1.0 mA) | TCVF | — | -8.64 | _ | mV/°C |

TYPICAL CHARACTERISTICS

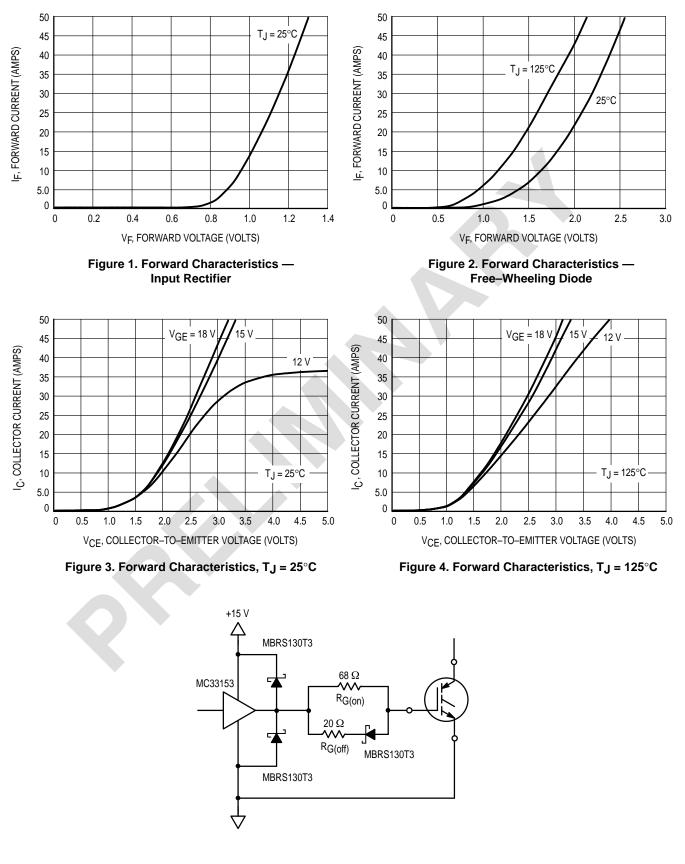
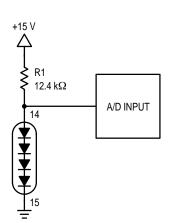


Figure 5. Recommended Gate Drive Circuit

TYPICAL CHARACTERISTICS



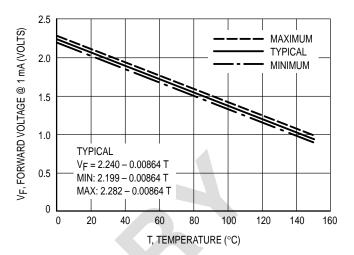
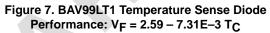
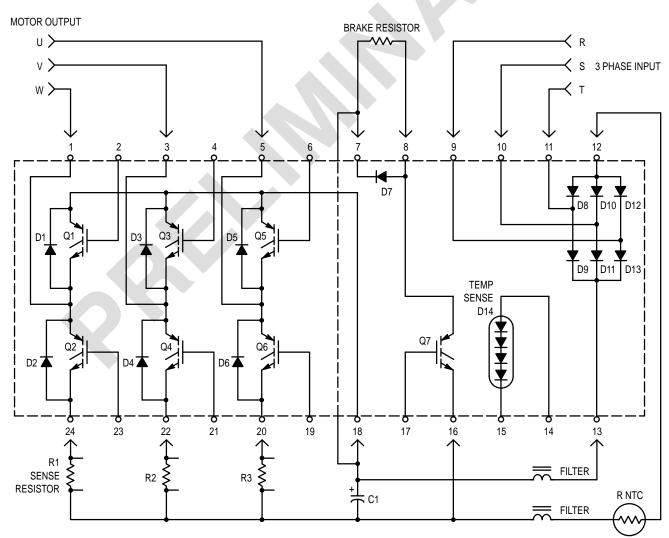


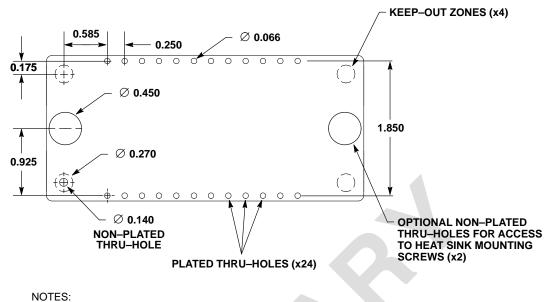
Figure 6. Recommended Temperature Sense Bias Circuit







MHPM7A25S120DC3

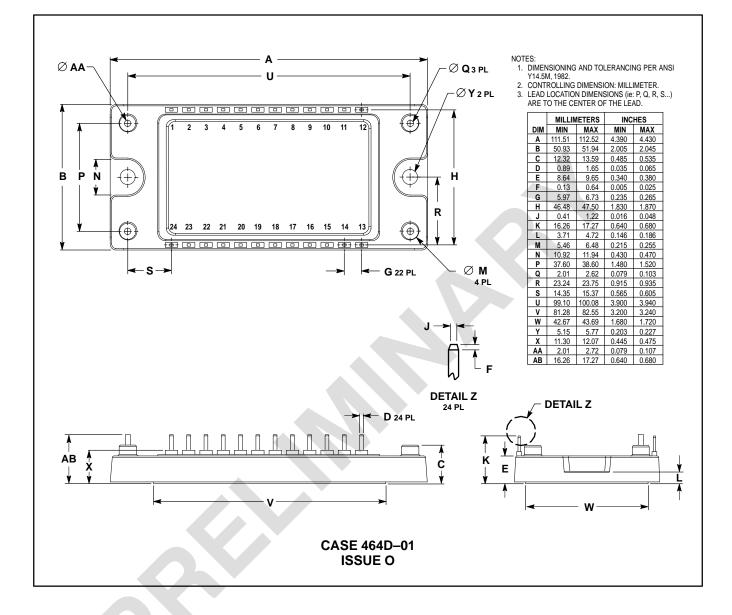


1. Package is symmetrical, except for a polarizing plastic post near pin 1, indicated by a non-plated thru-hole in the footprint.

- 2. Dimension of plated thru-holes indicates finished hole size after plating.
- 3. Access holes for mounting screws may or may not be necessary depending on assembly plan for finished product.

Figure 9. Package Footprint (Dimensions in Inches)

PACKAGE DIMENSIONS



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